## LITEON SEMICONDUCTOR

#### SURFACE MOUNT **GLASS PASSIVATED BRIDGE RECTIFIERS**

#### **FEATURES**

- Rating to 1200V PRV
- Ideal for printed circuit board
- Low forward voltage drop high current capability
- Reliable low cost construction utilizing molded
- plastic technique
- UL recognized file # E95060

#### **MECHANICAL DATA**

- · Case Material: molding compound, UL flammability classification 94V-0
- · Polarity: As marked on the body
- Mounting Position: Any
- Weight: 360mg (Approximate)

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

#### ABSOLUTE RATINGS

PARAMETER	SYMBOL	DF15005S	DF1501S	DF1502S	DF1504S	DF1506S	DF1508S	DF1510S	DF1512S	UNIT
Device marking code	Note	DF15005S	DF1501S	DF1502S	DF1504S	DF1506S	DF1508S	DF1510S	DF1512S	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	1200	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	1200	V
Average rectified output current per device @T <sub>c</sub> = 120°C	I <sub>(AV)</sub>	1.5				А				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC METHOD)	I <sub>FSM</sub>	50				A				
Peak forward surge current 1 ms single half sine-wave superimposed on rated load (JEDEC METHOD)	I <sub>FSM</sub>	100				A				
$I^2$ t rating for fusing (t < 8.3ms)	l²t	10.4			A <sup>2</sup> S					
Operating and storage temperature range	$T_{J}$ , $T_{STG}$	-55 to +150			°C					

#### STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST	CONDITION	SYMBOL	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 1.5A	T <sub>J</sub> = 25°C	V <sub>F</sub>	1.1	V
Leakage current	$V_{R}$ at rated	T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C	I <sub>R</sub>	10 500	uA
Typical junction capacita	NCE (Note 1)		CJ	25	pF

#### THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	TYP.	UNIT
Typical thermal resistance (Note 2)	RthJ <sub>A</sub> RthJ <sub>C</sub> RthJ <sub>L</sub>	40 8 20	°C/W
Note :	REV. 14, MAR2015, KE	DA02	

Note :

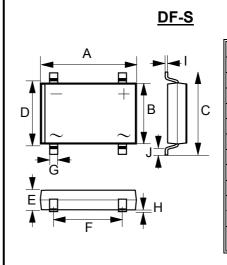
(1) Measured at 1.0MHz and applied reverse voltage of 4.0V DC

Thermal resistance junction to ambient, case and lead in accordance with JESD-51. Unit mounted on (2)

P.C.B with 0.5 x 0.5" (13 x 13 mm) copper pad per pin.

### **DF15005S thru DF1512S**

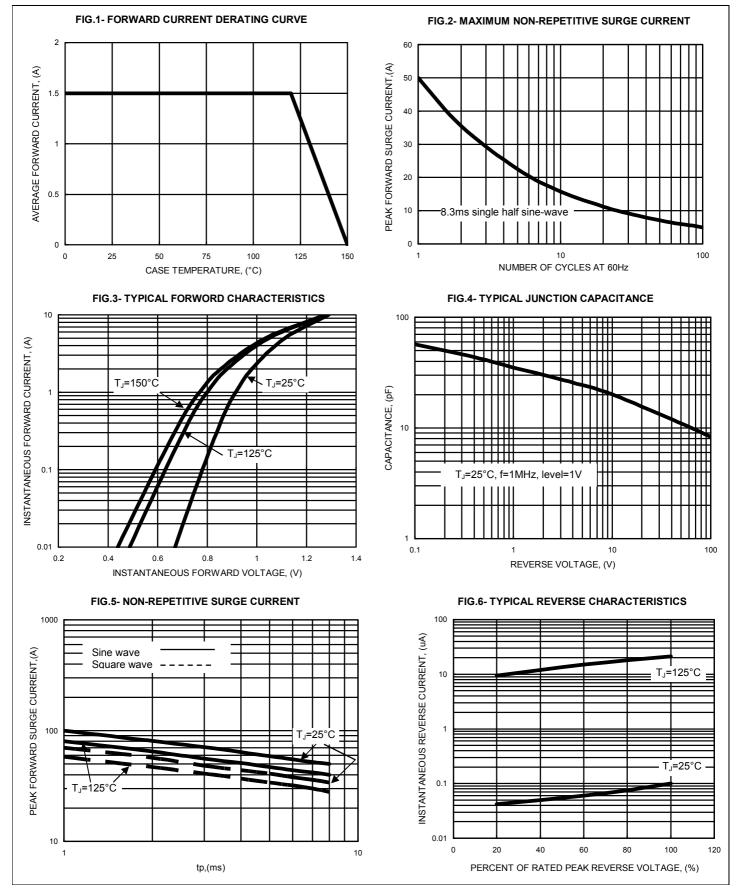
#### **REVERSE VOLTAGE – 50 to 1200 Volts FORWARD CURRENT – 1.5 Amperes**



	DF-S			
DIM	MIN	MAX		
Α	8.20	8.50		
В	6.20	6.50		
С	9.80	10.30		
D	7.40	7.90		
Е	2.40	2.60		
F	5.00	5.20		
G	1.00			
Н	.076	.330		
I	.220	.300		
J	1.02	1.53		
All dimension in millimeter				

## RATING AND CHARACTERISTIC CURVES DF1505S thru DF1512S

# LITEON



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